





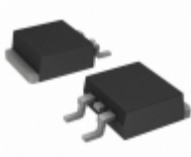

	<p>SUD19P06-60-GE3</p>
	<p>Hersteller-Teilenummer: SUD19P06-60-GE3</p> <hr/> <p>Hersteller / Marke: Vishay / Siliconix</p> <hr/> <p>Teil der Beschreibung: MOSFET P-CH 60V 18.3A TO-252</p> <hr/> <p>Datenblätter:  SUD19P06-60-GE3.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 50905 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SUD19P06-60-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET P-CH 60V 18.3A TO-252
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	50905 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	TO-252, (D-Pak)
Verlustleistung (max)	2.3W (Ta), 38.5W (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	18.3A (Tc)
Rds On (Max) @ Id, Vgs	60 mOhm @ 10A, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	40nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1710pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)


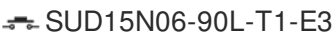





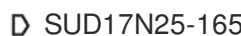



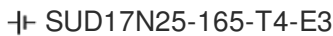



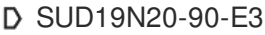

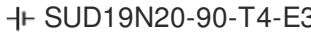
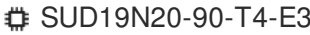

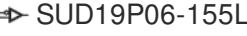











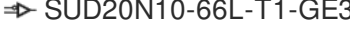

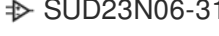
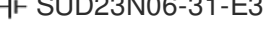
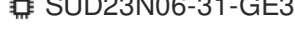
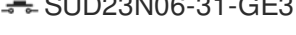
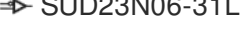
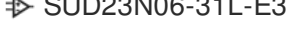
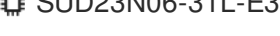
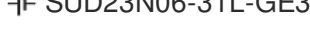
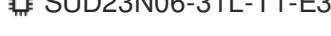
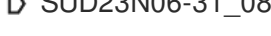
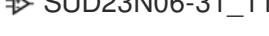
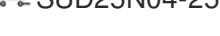
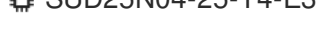
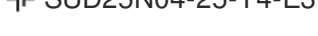
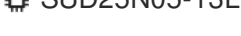
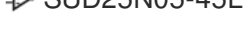
SUD19P06-60-GE3 ist neu im Original, Suche SUD19P06-60-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SUD19P06-60-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SUD19P06-60-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SUD20N03 S SUD20N03 S</p>	 <p>SUD19P06-60L-E3 Electro-Films (EFI) / Vishay MOSFET P-CH 60V 19A TO252</p>	 <p>SUD19P06-60-E3 Vishay / Siliconix MOSFET P-CH 60V 18.3A TO252</p>	 <p>SUD19P06-60-GE3 Electro-Films (EFI) / Vishay MOSFET P-CH 60V 18.3A TO-252</p>
 <p>SUD19P06-60 VISHAY SUD19P06-60 VISHAY</p>	 <p>SUD19P06-155L Vishay Precision Group SUD19P06-155L VISHAY</p>	 <p>SUD19P06-60L-E3 Vishay / Siliconix MOSFET P-CH 60V 19A TO252</p>	 <p>SUD19P06-60-E3 Electro-Films (EFI) / Vishay MOSFET P-CH 60V 18.3A TO252</p>

heiße Teile

Mehr

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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